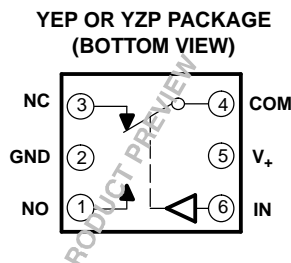
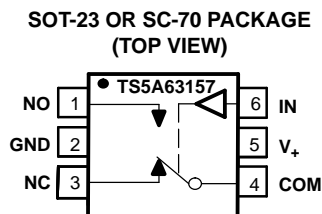


## FEATURES

- Overshoot and Undershoot Voltage Protection
- Isolation in Powered-Off Mode,  $V_+ = 0$
- Specified Break-Before-Make Switching
- Low ON-State Resistance (12 Ω)
- Control Inputs Are 5-V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)

## APPLICATIONS

- Sample-and-Hold Circuits
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits



## DESCRIPTION/ORDERING INFORMATION

The TS5A63157 is a single-pole, double-throw (SPDT) analog switch designed to operate from 1.65 V to 5.5 V. This device can handle both digital and analog signals. Signals up to  $V_+$  (peak) can be transmitted in either direction.

TI has integrated overshoot and undershoot protection circuitry. The TS5A63157 senses overshoot and undershoot events at the I/Os and responds by preventing voltage differentials from developing and turning the switch on.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar, NanoFree are trademarks of Texas Instruments.

**SUMMARY OF CHARACTERISTICS**  
 $V_+ = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$

|   |   |
|---|---|
| Configuration                                   | Single 2:1 Multiplexer/<br>Demultiplexer (1 × SPDT) |
| Number of channels                              | 1   |
| ON-state resistance ( $r_{on}$ )                | 12 Ω  |
| ON-state resistance match ( $\Delta r_{on}$ )   | 0.15 Ω  |
| ON-state resistance flatness ( $r_{on(Flat)}$ ) | 6 Ω   |
| Turn-on/turn-off time ( $t_{ON}/t_{OFF}$ )      | 5.7 ns/3.8 ns                                       |
| Break-before-make time ( $t_{BBM}$ )            | 0.5 ns  |
| Charge injection ( $Q_C$ )                      | 7 pC  |
| Bandwidth (BW)                                  | 250 MHz   |
| OFF isolation ( $O_{ISO}$ )                     | –57 dB at 10 MHz                                    |
| Crosstalk ( $X_{TALK}$ )                        | –54 dB at 10 MHz                                    |
| Total harmonic distortion (THD)                 | 0.01%   |
| Leakage current ( $I_{NO(OFF)}/I_{NC(OFF)}$ )   | ±1 μA   |
| Power-supply current ( $I_+$ )                  | 10 μA   |
| Undershoot protection                           | –2 V  |
| Overshoot protection                            | $V_+ + 2\text{ V}$                                  |
| Package options                                 | 6-pin SOT-23, SC-70,<br>and DSBGA                   |

**ORDERING INFORMATION**

| $T_A$         | PACKAGE <sup>(1)</sup>  |               | ORDERABLE PART NUMBER        | TOP-SIDE MARKING <sup>(2)</sup> |
|---------------|---|---------------|------------------------------|---------------------------------|
| –40°C to 85°C | NanoStar™ – WCSP (DSBGA)<br>0.23-mm Large Bump – YEP              | Tape and reel | TS5A63157YEPR <sup>(3)</sup> | PREVIEW                         |
|               | NanoFree™ – WCSP (DSBGA)<br>0.23-mm Large Bump – YZP<br>(Pb-free) | Tape and reel | TS5A63157YZPR <sup>(3)</sup> |                                 |
|               | SOT (SOT-23) – DBV  | Tape and reel | TS5A63157DBVR                | JBE_                            |
|               | SOT (SC-70) – DCK   | Tape and reel | TS5A63157DCKR                | J7_                             |

- (1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).
- (2) DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.  
YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, · = Pb-free).
- (3) Package preview

**FUNCTION TABLE**

| IN | NC TO COM,<br>COM TO NC | NO TO COM,<br>COM TO NO |
|----|-------------------------|-------------------------|
| L  | ON                      | OFF                     |
| H  | OFF                     | ON                      |

## Absolute Minimum and Maximum Ratings<sup>(1)(2)</sup>

over operating free-air temperature range (unless otherwise noted)

|                                   |   |  | MIN  | MAX         | UNIT |
|-----------------------------------|---|--|------|-------------|------|
| $V_+$                             | Supply voltage range <sup>(3)</sup>           |  | −0.5 | 6.5         | V    |
| $V_{NO}$<br>$V_{NC}$<br>$V_{COM}$ | Analog voltage range <sup>(3)(4)(5)</sup>     |  | −0.5 | $V_+ + 0.5$ | V    |
| $I_K$                             | Analog port diode current                     | $V_{NC}, V_{NO}, V_{COM} < 0$ or $V_{NO}, V_{NC}, V_{COM} > V_+$ | −50  | 50          | mA   |
| $I_{NO}$<br>$I_{NC}$<br>$I_{COM}$ | On-state switch current                       | $V_{NC}, V_{NO}, V_{COM} = 0$ to $V_+$                           | −50  | 50          | mA   |
| $V_I$                             | Digital input voltage range <sup>(3)(4)</sup> |  | −0.5 | 6.5         | V    |
| $I_{IK}$                          | Digital input clamp current                   | $V_I < 0$  | −50  |             | mA   |
| $I_+$                             | Continuous current through $V_+$              |  | −100 | 100         | mA   |
| $I_{GND}$                         | Continuous current through GND                |  | −100 | 100         | mA   |
| $\theta_{JA}$                     | Package thermal impedance                     | DBV package <sup>(6)</sup>                                       |      | 206         | °C/W |
|                                   |   | DCK package <sup>(6)</sup>                                       |      | 252         |      |
|                                   |   | YEA/YZA package <sup>(6)</sup>                                   |      | 143         |      |
|                                   |   | YEP/YZP package <sup>(7)</sup>                                   |      | 123         |      |
| $T_{stg}$                         | Storage temperature range                     |  | −65  | 150         | °C   |

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.
- (7) The package thermal impedance is calculated in accordance with JESD 51-5.

**TS5A63157**  
**12-Ω SPDT ANALOG SWITCH**  
**5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER**

SCDS203–DECEMBER 2005

**Electrical Characteristics for 5-V Supply**

$V_+ = 4.5 \text{ V to } 5.5 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                  | SYMBOL                           | TEST CONDITIONS   | $T_A$        | $V_+$ | MIN              | TYP   | MAX              | UNIT          |
|--|----------------------------------|---|--------------|-------|------------------|-------|------------------|---------------|
| <b>Analog Switch</b>                       |                                  |   |              |       |                  |       |                  |               |
| Analog signal range                        | $V_{COM}, V_{NO}, V_{NC}$        |   |              |       | 0                |       | $V_+$            | V             |
| Voltage undershoot                         | $V_{IKU}$                        | $0 \geq (I_{NC}, I_{NO}, \text{ or } I_{COM}) \geq -50 \text{ mA}$  |              | 5.5 V |                  |       | -2               | V             |
| Peak ON-state resistance                   | $r_{peak}$                       | $0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$ ,<br>$I_{COM} = -30 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13  | 25°C<br>Full | 4.5 V |                  | 4.6   | 11<br>13         | $\Omega$      |
| ON-state resistance                        | $r_{on}$                         | $V_{NO} \text{ or } V_{NC} = 0$ ,<br>$I_{COM} = 30 \text{ mA}$<br><br>$V_{NO} \text{ or } V_{NC} = 2.4 \text{ V}$ ,<br>$I_{COM} = -30 \text{ mA}$<br><br>$V_{NO} \text{ or } V_{NC} = 4.5 \text{ V}$ ,<br>$I_{COM} = -30 \text{ mA}$<br>Switch ON,<br>See Figure 13 | 25°C         | 4.5 V |                  | 4     | 6.5              | $\Omega$      |
|  |                                  |   | Full         |       |                  |       | 8                |               |
|  |                                  |   | 25°C         |       |                  | 4     | 8                |               |
|  |                                  |   | Full         |       |                  |       | 10               |               |
|  |                                  |   | 25°C         |       |                  | 5.5   | 10               |               |
|  |                                  |   | Full         |       |                  |       | 12               |               |
| ON-state resistance match between channels | $\Delta r_{on}$                  | $V_{NO} \text{ or } V_{NC} = 3.15 \text{ V}$ ,<br>$I_{COM} = -30 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13   | 25°C<br>Full | 4.5 V |                  | 0.1   | 0.14<br>0.15     | $\Omega$      |
| ON-state resistance flatness               | $r_{on(flat)}$                   | $0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$ ,<br>$I_{COM} = -30 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13  | 25°C<br>Full | 4.5 V |                  | 1.5   | 2<br>4           | $\Omega$      |
| NC, NO OFF leakage current                 | $I_{NC(OFF)}, I_{NO(OFF)}$       | $V_{NC} \text{ or } V_{NO} = 0 \text{ to } V_+$ ,<br>$V_{COM} = V_+ \text{ to } 0$ ,<br>Switch OFF,<br>See Figure 14  | 25°C         | 5.5 V |                  | 0.001 | 0.03             | $\mu\text{A}$ |
|  |                                  |   | Full         |       |                  |       | 0.05             |               |
|  | $I_{NC(PWROFF)}, I_{NO(PWROFF)}$ | $V_{NC} \text{ or } V_{NO} = 0 \text{ to } 5.5 \text{ V}$ ,<br>$V_{COM} = 5.5 \text{ V to } 0$ ,<br>Switch OFF,<br>See Figure 14  | 25°C         | 0     |                  | 0.15  | 1                |               |
|  |                                  |   | Full         |       |                  |       | 5                |               |
| COM OFF leakage current                    | $I_{COM(PWROFF)}$                | $V_{COM} = 0 \text{ to } 5.5 \text{ V}$ ,<br>$V_{NC} \text{ or } V_{NO} = 5.5 \text{ V to } 0$ ,<br>Switch ON,<br>See Figure 14   | 25°C<br>Full | 0     |                  | 0.2   | 1<br>10          | $\mu\text{A}$ |
| NC, NO ON leakage current                  | $I_{NC(ON)}, I_{NO(ON)}$         | $V_{NC} \text{ or } V_{NO} = 0 \text{ to } V_+$ ,<br>$V_{COM} = \text{Open}$ ,<br>Switch ON,<br>See Figure 15   | 25°C<br>Full | 5.5 V |                  | 0.001 | 0.01<br>0.02     | $\mu\text{A}$ |
| COM ON leakage current                     | $I_{COM(ON)}$                    | $V_{NC} \text{ or } V_{NO} = \text{Open}$ ,<br>$V_{COM} = 0 \text{ to } V_+$ ,<br>Switch ON,<br>See Figure 15   | 25°C<br>Full | 5.5 V |                  | 0.003 | 0.03<br>0.05     | $\mu\text{A}$ |
| <b>Digital Control Input (IN)</b>          |                                  |   |              |       |                  |       |                  |               |
| Input logic high                           | $V_{IH}$                         |   | Full         |       | $V_+ \times 0.7$ |       | 5.5              | V             |
| Input logic low                            | $V_{IL}$                         |   | Full         |       | 0                |       | $V_+ \times 0.3$ | V             |
| Input leakage current                      | $I_{IH}, I_{IL}$                 | $V_I = 5.5 \text{ V or } 0$   | 25°C         | 5.5 V |                  | 0.05  | 0.1              | $\mu\text{A}$ |
|  |                                  |   | Full         |       |                  |       | 0.02             |               |

## Electrical Characteristics for 5-V Supply (continued)

$V_+ = 4.5\text{ V to }5.5\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                        | SYMBOL                           | TEST CONDITIONS   | $T_A$ | $V_+$             | MIN | TYP            | MAX  | UNIT          |
|----------------------------------|----------------------------------|---|-------|-------------------|-----|----------------|------|---------------|
| <b>Dynamic</b>                   |                                  |   |       |                   |     |                |      |               |
| Turn-on time                     | $t_{ON}$                         | $V_{COM} = V_+$ or GND,<br>$R_L = 500\ \Omega$ ,<br>$C_L = 50\text{ pF}$ ,<br>See Figure 17               | 25°C  | 5 V               | 2   | 3.4            | 5    | ns            |
|                                  |                                  |   | Full  | 4.5 V to<br>5.5 V | 2   |                | 5.5  |               |
| Turn-off time                    | $t_{OFF}$                        | $V_{COM} = V_+$ or GND,<br>$R_L = 500\ \Omega$ ,<br>$C_L = 50\text{ pF}$ ,<br>See Figure 17               | 25°C  | 5 V               | 1   | 2.8            | 3.4  | ns            |
|                                  |                                  |   | Full  | 4.5 V to<br>5.5 V | 1   |                | 3.8  |               |
| Output voltage during undershoot | $V_{OUTU}$                       | See Figure 18   |       |                   | 2.5 | $V_{OH} - 0.3$ |      | V             |
| Output voltage during overshoot  | $V_{OUTO}$                       | See Figure 18   |       |                   |     | $V_{OL} + 0.3$ | 2    | V             |
| Break-before-make time           | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$ ,<br>$R_L = 50\ \Omega$ ,<br>$C_L = 50\text{ pF}$ ,<br>See Figure 19            | 25°C  | 5 V               | 0.5 | 5              | 12   | ns            |
|                                  |                                  |   | Full  | 4.5 V to<br>5.5 V | 0.5 |                | 14   |               |
| Charge injection                 | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,<br>$C_L = 0.1\text{ nF}$ ,<br>See Figure 23                            | 25°C  | 5 V               |     | -21            |      | pC            |
| NC, NO OFF capacitance           | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch OFF,<br>See Figure 16  | 25°C  | 5 V               |     | 5              |      | pF            |
| NC, NO ON capacitance            | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch ON,<br>See Figure 16   | 25°C  | 5 V               |     | 14.5           |      | pF            |
| COM ON capacitance               | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,<br>See Figure 16  | 25°C  | 5 V               |     | 14.5           |      | pF            |
| Digital input capacitance        | $C_I$                            | $V_I = V_+$ or GND,<br>See Figure 16  | 25°C  | 5 V               |     | 2.5            |      | pF            |
| Bandwidth                        | BW                               | $R_L = 50\ \Omega$ ,<br>Switch ON,<br>See Figure 20   | 25°C  | 5 V               |     | 371            |      | MHz           |
| OFF isolation                    | $O_{ISO}$                        | $R_L = 50\ \Omega$ ,<br>$f = 10\text{ MHz}$ ,<br>Switch OFF,<br>See Figure 21                             | 25°C  | 5 V               |     | -61            |      | dB            |
| Crosstalk                        | $X_{TALK}$                       | $R_L = 50\ \Omega$ ,<br>$f = 10\text{ MHz}$ ,<br>Switch ON,<br>See Figure 22                              | 25°C  | 5 V               |     | -61            |      | dB            |
| Total harmonic distortion        | THD                              | $R_L = 600\ \Omega$ ,<br>$C_L = 50\text{ pF}$ ,<br>$f = 20\text{ Hz to }20\text{ kHz}$ ,<br>See Figure 24 | 25°C  | 5 V               |     | 0.06           |      | %             |
| <b>Supply</b>                    |                                  |   |       |                   |     |                |      |               |
| Positive supply current          | $I_+$                            | $V_I = V_+$ or GND,<br>Switch ON or OFF   | 25°C  | 5.5 V             |     | 0.01           | 0.1  | $\mu\text{A}$ |
|                                  |                                  |   | Full  |                   |     |                | 0.75 |               |

**TS5A63157**  
**12-Ω SPDT ANALOG SWITCH**  
**5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER**

SCDS203–DECEMBER 2005

**Electrical Characteristics for 3.3-V Supply**

$V_+ = 3\text{ V to }3.6\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                  | SYMBOL   | TEST CONDITIONS  |                              | T <sub>A</sub> | V <sub>+</sub> | MIN                     | TYP  | MAX                     | UNIT |
|--|--|--|------------------------------|----------------|----------------|-------------------------|------|-------------------------|------|
| Analog Switch                              |  |  |                              |                |                |                         |      |                         |      |
| Analog signal range                        | V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub> |  |                              |                |                | 0                       |      | V <sub>+</sub>          | V    |
| Voltage undershoot                         | V <sub>IKU</sub>                                     | 0 ≥ (I <sub>NC</sub> , I <sub>NO</sub> , or I <sub>COM</sub> ) ≥ − 50 mA                             |                              |                | 3.6 V          |                         |      |                         | V    |
| Peak ON-state resistance                   | r <sub>peak</sub>                                    | 0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>+</sub> ,<br>I <sub>COM</sub> = −24 mA,           | Switch ON,<br>See Figure 13  | 25°C<br>Full   | 3 V            | 6.4                     | 14   | 18                      | Ω    |
| ON-state resistance                        | r <sub>on</sub>                                      | V <sub>NO</sub> or V <sub>NC</sub> = 0,<br>I <sub>COM</sub> = 24 mA                                  | Switch ON,<br>See Figure 13  | 25°C           | 3 V            | 4.8                     | 8    |                         | Ω    |
|  |  |  |                              | Full           |                | 10                      |      |                         |      |
|  |  | V <sub>NO</sub> or V <sub>NC</sub> = 3 V,<br>I <sub>COM</sub> = −24 mA                               |                              | 25°C           |                | 6.3                     | 12   |                         |      |
|  |  |  |                              | Full           |                | 15                      |      |                         |      |
| ON-state resistance match between channels | Δr <sub>on</sub>                                     | V <sub>NO</sub> or V <sub>NC</sub> = 2.1 V,<br>I <sub>COM</sub> = −24 mA,                            | Switch ON,<br>See Figure 13  | 25°C<br>Full   | 3 V            | 0.1                     | 0.2  | 0.2                     | Ω    |
| ON-state resistance flatness               | r <sub>on(flat)</sub>                                | 0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>+</sub> ,<br>I <sub>COM</sub> = −24 mA,           | Switch ON,<br>See Figure 13  | 25°C<br>Full   | 3 V            | 2.8                     | 4    | 7                       | Ω    |
| NC, NO OFF leakage current                 | I <sub>NC(OFF)</sub> ,<br>I <sub>NO(OFF)</sub>       | V <sub>NC</sub> or V <sub>NO</sub> = 0 to V <sub>+</sub> ,<br>V <sub>COM</sub> = V <sub>+</sub> to 0 | Switch OFF,<br>See Figure 14 | 25°C           | 3.6 V          | 0                       | 0.03 | μA                      |      |
|  |  |  |                              | Full           |                | 0.05                    |      |                         |      |
|  | I <sub>NC(PWROFF)</sub> ,<br>I <sub>NO(PWROFF)</sub> | V <sub>NC</sub> or V <sub>NO</sub> = 0 to 3.6 V,<br>V <sub>COM</sub> = 3.6 V to 0,                   | Switch OFF,<br>See Figure 14 | 25°C           | 0              | 0.15                    | 0.05 |                         |      |
|  |  |  |                              | Full           |                | 2                       |      |                         |      |
| COM OFF leakage current                    | I <sub>COM(PWROFF)</sub>                             | V <sub>COM</sub> = 0 to 3.6 V,<br>V <sub>NC</sub> or V <sub>NO</sub> = 3.6 V to 0,                   | Switch ON,<br>See Figure 14  | 25°C<br>Full   | 0              | 0.2                     | 0.05 | 5                       | μA   |
| NC, NO ON leakage current                  | I <sub>NC(ON)</sub> ,<br>I <sub>NO(ON)</sub>         | V <sub>NC</sub> or V <sub>NO</sub> = 0 to V <sub>+</sub> ,<br>V <sub>COM</sub> = Open,               | Switch ON,<br>See Figure 15  | 25°C           | 3.6 V          | −0.1                    | 0.05 | 0.1                     | μA   |
|  |  |  |                              | Full           |                | −1                      | 1    |                         |      |
| COM ON leakage current                     | I <sub>COM(ON)</sub>                                 | V <sub>NC</sub> or V <sub>NO</sub> = Open,<br>V <sub>COM</sub> = 0 to V <sub>+</sub> ,               | Switch ON,<br>See Figure 15  | 25°C<br>Full   | 3.6 V          | 0.003                   | 0.03 | 0.05                    | μA   |
| Digital Control Input (IN)                 |  |  |                              |                |                |                         |      |                         |      |
| Input logic high                           | V <sub>IH</sub>                                      |  |                              | Full           |                | V <sub>+</sub><br>× 0.7 |      | 5.5                     | V    |
| Input logic low                            | V <sub>IL</sub>                                      |  |                              | Full           |                | 0                       |      | V <sub>+</sub><br>× 0.3 | V    |
| Input leakage current                      | I <sub>IH</sub> , I <sub>IL</sub>                    | V <sub>I</sub> = 5.5 V or 0  |                              | 25°C<br>Full   | 3.6 V          | 0.005                   | 0.01 | 0.02                    | μA   |

## Electrical Characteristics for 3.3-V Supply (continued)

$V_+ = 3\text{ V to }3.6\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                        | SYMBOL   | TEST CONDITIONS  |   | T <sub>A</sub> | V <sub>+</sub> | MIN   | TYP                   | MAX  | UNIT   |
|----------------------------------|--|--|---|----------------|----------------|-------|-----------------------|------|--------|
| Dynamic                          |  |  |   |                |                |       |                       |      |        |
| Turn-on time                     | t <sub>ON</sub>                                | V <sub>COM</sub> = V <sub>+</sub> or GND,<br>R <sub>L</sub> = 500 Ω,             | C <sub>L</sub> = 50 pF,<br>See Figure 17  | 25°C           | 3.3 V          | 2     | 4.3                   | 6.6  | ns     |
|                                  |  |  |   | Full           | 3 V to 3.6 V   | 2     |                       | 7    |        |
| Turn-off time                    | t <sub>OFF</sub>                               | V <sub>COM</sub> = V <sub>+</sub> or GND,<br>R <sub>L</sub> = 500 Ω,             | C <sub>L</sub> = 50 pF,<br>See Figure 17  | 25°C           | 3.3 V          | 1     | 3.3                   | 6.3  | ns     |
|                                  |  |  |   | Full           | 3 V to 3.6 V   | 1     |                       | 7    |        |
| Output voltage during undershoot | V <sub>OUTU</sub>                              | See Figure 18  |   |                |                | 2.5   | V <sub>OH</sub> − 0.3 |      | V      |
| Output voltage during overshoot  | V <sub>OUTO</sub>                              | See Figure 18  |   |                |                |       | V <sub>OL</sub> + 0.3 |      | 2<br>V |
| Break-before-make time           | t <sub>BBM</sub>                               | V <sub>NC</sub> = V <sub>NO</sub> = V <sub>+</sub> /2,<br>R <sub>L</sub> = 50 Ω, | C <sub>L</sub> = 50 pF,<br>See Figure 19  | 25°C           | 3.3 V          | 0.5   | 7                     | 17   | ns     |
|                                  |  |  |   | Full           | 3 V to 3.6 V   | 0.5   |                       | 19.5 |        |
| Charge injection                 | Q <sub>C</sub>                                 | V <sub>GEN</sub> = 0,<br>R <sub>GEN</sub> = 0,                                   | C <sub>L</sub> = 0.1 nF,<br>See Figure 23 | 25°C           | 3.3 V          | −11.5 |                       |      | pC     |
| NC, NO OFF capacitance           | C <sub>NC(OFF)</sub> ,<br>C <sub>NO(OFF)</sub> | V <sub>NC</sub> or V <sub>NO</sub> = V <sub>+</sub> or GND,<br>Switch OFF,       | See Figure 16                             | 25°C           | 3.3 V          | 5     |                       |      | pF     |
| NC, NO ON capacitance            | C <sub>NC(ON)</sub> ,<br>C <sub>NO(ON)</sub>   | V <sub>NC</sub> or V <sub>NO</sub> = V <sub>+</sub> or GND,<br>Switch ON,        | See Figure 16                             | 25°C           | 3.3 V          | 15    |                       |      | pF     |
| COM ON capacitance               | C <sub>COM(ON)</sub>                           | V <sub>COM</sub> = V <sub>+</sub> or GND,<br>Switch ON,                          | See Figure 16                             | 25°C           | 3.3 V          | 15    |                       |      | pF     |
| Digital input capacitance        | C <sub>I</sub>                                 | V <sub>I</sub> = V <sub>+</sub> or GND,  | See Figure 16                             | 25°C           | 3.3 V          | 2.5   |                       |      | pF     |
| Bandwidth                        | BW   | R <sub>L</sub> = 50 Ω,<br>Switch ON,   | See Figure 20                             | 25°C           | 3.3 V          | 370   |                       |      | MHz    |
| OFF isolation                    | O <sub>ISO</sub>                               | R <sub>L</sub> = 50 Ω,<br>f = 10 MHz,  | Switch OFF,<br>See Figure 21              | 25°C           | 3.3 V          | −60   |                       |      | dB     |
| Crosstalk                        | X <sub>TALK</sub>                              | R <sub>L</sub> = 50 Ω,<br>f = 10 MHz,  | Switch ON,<br>See Figure 22               | 25°C           | 3.3 V          | −60   |                       |      | dB     |
| Total harmonic distortion        | THD  | R <sub>L</sub> = 600 Ω,<br>C <sub>L</sub> = 50 pF,                               | f = 20 Hz to 20 kHz,<br>See Figure 24     | 25°C           | 3.3 V          | 0.1   |                       |      | %      |
| Supply                           |  |  |   |                |                |       |                       |      |        |
| Positive supply current          | I <sub>+</sub>                                 | V <sub>I</sub> = V <sub>+</sub> or GND,  | Switch ON or OFF                          | 25°C           | 3.6 V          | 0.05  |                       | 0.1  | μA     |
|                                  |  |  |   | Full           |                | 0.6   |                       |      |        |

**TS5A63157**  
**12-Ω SPDT ANALOG SWITCH**  
**5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER**

SCDS203–DECEMBER 2005

**Electrical Characteristics for 2.5-V Supply**

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                  | SYMBOL   | TEST CONDITIONS  | $T_A$        | $V_+$ | MIN               | TYP   | MAX               | UNIT          |
|--|--|--|--------------|-------|-------------------|-------|-------------------|---------------|
| <b>Analog Switch</b>                       |  |  |              |       |                   |       |                   |               |
| Analog signal range                        | $V_{\text{COM}}, V_{\text{NO}}, V_{\text{NC}}$ |  |              |       | 0                 |       | $V_+$             | V             |
| Voltage undershoot                         | $V_{\text{IKU}}$                               | $0 \text{ mA} \geq (I_{\text{NC}}, I_{\text{NO}}, \text{ or } I_{\text{COM}}) \geq -50 \text{ mA}$   |              | 2.7 V |                   |       |                   | V             |
| Peak ON-state resistance                   | $r_{\text{peak}}$                              | $0 \leq (V_{\text{NO}} \text{ or } V_{\text{NC}}) \leq V_+$ ,<br>$I_{\text{COM}} = -8 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13   | 25°C<br>Full | 2.3 V |                   | 9.2   | 30<br>35          | $\Omega$      |
| ON-state resistance                        | $r_{\text{on}}$                                | $V_{\text{NO}} \text{ or } V_{\text{NC}} = 0$ ,<br>$I_{\text{COM}} = 8 \text{ mA}$<br><br>$V_{\text{NO}} \text{ or } V_{\text{NC}} = 2.3 \text{ V}$ ,<br>$I_{\text{COM}} = -8 \text{ mA}$<br>Switch ON,<br>See Figure 13 | 25°C         | 2.3 V |                   | 5.4   | 8.5               | $\Omega$      |
|  |  |  | Full         |       |                   |       | 12                |               |
|  |  |  | 25°C         |       |                   | 8.6   | 15.5              |               |
|  |  |  | Full         |       |                   |       | 25                |               |
| ON-state resistance match between channels | $\Delta r_{\text{on}}$                         | $V_{\text{NO}} \text{ or } V_{\text{NC}} = 1.6 \text{ V}$ ,<br>$I_{\text{COM}} = -8 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13   | 25°C<br>Full | 2.3 V |                   | 0.05  | 0.3<br>0.5        | $\Omega$      |
| ON-state resistance flatness               | $r_{\text{on(flat)}}$                          | $0 \leq (V_{\text{NO}} \text{ or } V_{\text{NC}}) \leq V_+$ ,<br>$I_{\text{COM}} = -8 \text{ mA}$ ,<br>Switch ON,<br>See Figure 13   | 25°C<br>Full | 2.3 V |                   | 5     | 9<br>15           | $\Omega$      |
| NC, NO OFF leakage current                 | $I_{\text{NC(OFF)}}, I_{\text{NO(OFF)}}$       | $V_{\text{NC}} \text{ or } V_{\text{NO}} = 0 \text{ to } V_+$ ,<br>$V_{\text{COM}} = V_+ \text{ to } 0$ ,<br>Switch OFF,<br>See Figure 14  | 25°C         | 2.7 V |                   | 0     | 0.03              | $\mu\text{A}$ |
|  |  |  | Full         |       |                   |       | 0.05              |               |
|  | $I_{\text{NC(PWROFF)}}, I_{\text{NOPWROFF}}$   | $V_{\text{NC}} \text{ or } V_{\text{NO}} = 0 \text{ to } 2.7 \text{ V}$ ,<br>$V_{\text{COM}} = 2.7 \text{ V to } 0$ ,<br>Switch OFF,<br>See Figure 14  | 25°C         | 0     |                   | 0.15  | 0.05              |               |
|  |  |  | Full         |       |                   |       | 0.75              |               |
| COM OFF leakage current                    | $I_{\text{COM(PWROFF)}}$                       | $V_{\text{COM}} = 0 \text{ to } 2.7 \text{ V}$ ,<br>$V_{\text{NC}} \text{ or } V_{\text{NO}} = 2.7 \text{ V to } 0$ ,<br>Switch ON,<br>See Figure 14   | 25°C<br>Full | 0     |                   | 0.2   | 0.5<br>1          | $\mu\text{A}$ |
| NC, NO ON leakage current                  | $I_{\text{NC(ON)}}, I_{\text{NO(ON)}}$         | $V_{\text{NC}} \text{ or } V_{\text{NO}} = 0 \text{ to } V_+$ ,<br>$V_{\text{COM}} = \text{Open}$ ,<br>Switch ON,<br>See Figure 15   | 25°C<br>Full | 2.7 V |                   | 0.001 | 0.01<br>0.02      | $\mu\text{A}$ |
| COM ON leakage current                     | $I_{\text{COM(ON)}}$                           | $V_{\text{NC}} \text{ or } V_{\text{NO}} = \text{Open}$ ,<br>$V_{\text{COM}} = 0 \text{ to } V_+$ ,<br>Switch ON,<br>See Figure 15   | 25°C<br>Full | 2.7 V |                   | 0.003 | 0.03<br>0.05      | $\mu\text{A}$ |
| <b>Digital Control Input (IN)</b>          |  |  |              |       |                   |       |                   |               |
| Input logic high                           | $V_{\text{IH}}$                                |  | Full         |       | $V_+ \times 0.75$ |       | 5.5               | V             |
| Input logic low                            | $V_{\text{IL}}$                                |  | Full         |       | 0                 |       | $V_+ \times 0.25$ | V             |
| Input leakage current                      | $I_{\text{IH}}, I_{\text{IL}}$                 | $V_{\text{I}} = 5.5 \text{ V or } 0$   | 25°C         | 2.7 V |                   | 0.005 | 0.01              | $\mu\text{A}$ |
|  |  |  | Full         |       |                   |       | 0.02              |               |



## Electrical Characteristics for 2.5-V Supply (continued)

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                        | SYMBOL                           | TEST CONDITIONS  | $T_A$ | $V_+$          | MIN | TYP            | MAX  | UNIT |
|----------------------------------|----------------------------------|--|-------|----------------|-----|----------------|------|------|
| <b>Dynamic</b>                   |                                  |  |       |                |     |                |      |      |
| Turn-on time                     | $t_{ON}$                         | $V_{COM} = V_+$ or GND,<br>$R_L = 500 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 17                  | 25°C  | 2.5 V          | 3   | 5.8            | 9.6  | ns   |
|                                  |                                  |  | Full  | 2.3 V to 2.7 V | 3   |                | 12   |      |
| Turn-off time                    | $t_{OFF}$                        | $V_{COM} = V_+$ or GND,<br>$R_L = 500 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 17                  | 25°C  | 2.5 V          | 1.5 | 4.5            | 7.3  | ns   |
|                                  |                                  |  | Full  | 2.3 V to 2.7 V | 1.5 |                | 7.5  |      |
| Output voltage during undershoot | $V_{OUTU}$                       | See Figure 18  |       |                | 2.5 | $V_{OH} - 0.3$ |      | V    |
| Output voltage during overshoot  | $V_{OUTO}$                       | See Figure 18  |       |                |     | $V_{OL} + 0.3$ | 2    | V    |
| Break-before-make time           | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$ ,<br>$R_L = 50 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 19               | 25°C  | 2.5 V          | 0.5 | 10             | 25   | ns   |
|                                  |                                  |  | Full  | 2.3 V to 2.7 V | 0.5 |                | 28.5 |      |
| Charge injection                 | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,<br>$C_L = 0.1 \text{ nF}$ ,<br>See Figure 23                              | 25°C  | 2.5 V          |     | -8             |      | pC   |
| NC, NO OFF capacitance           | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch OFF,<br>See Figure 16   | 25°C  | 2.5 V          |     | 5              |      | pF   |
| NC, NO ON capacitance            | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch ON,<br>See Figure 16  | 25°C  | 2.5 V          |     | 15             |      | pF   |
| COM ON capacitance               | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,<br>See Figure 16   | 25°C  | 2.5 V          |     | 15             |      | pF   |
| Digital input capacitance        | $C_I$                            | $V_I = V_+$ or GND,<br>See Figure 16   | 25°C  | 2.5 V          |     | 2.5            |      | pF   |
| Bandwidth                        | BW                               | $R_L = 50 \Omega$ ,<br>Switch ON,<br>See Figure 20   | 25°C  | 2.5 V          |     | 367            |      | MHz  |
| OFF isolation                    | $O_{ISO}$                        | $R_L = 50 \Omega$ ,<br>$f = 10 \text{ MHz}$ ,<br>Switch OFF,<br>See Figure 21                                | 25°C  | 2.5 V          |     | -60            |      | dB   |
| Crosstalk                        | $X_{TALK}$                       | $R_L = 50 \Omega$ ,<br>$f = 10 \text{ MHz}$ ,<br>Switch ON,<br>See Figure 22                                 | 25°C  | 2.5 V          |     | -60            |      | dB   |
| Total harmonic distortion        | THD                              | $R_L = 600 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>$f = 20 \text{ Hz to } 20 \text{ kHz}$ ,<br>See Figure 24 | 25°C  | 2.5 V          |     | 0.15           |      | %    |
| <b>Supply</b>                    |                                  |  |       |                |     |                |      |      |
| Positive supply current          | $I_+$                            | $V_I = V_+$ or GND,<br>Switch ON or OFF  | 25°C  | 2.7 V          |     | 0.05           | 0.1  | nA   |
|                                  |                                  |  | Full  |                |     |                | 0.5  |      |

**TS5A63157**  
**12-Ω SPDT ANALOG SWITCH**  
**5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER**

SCDS203–DECEMBER 2005

**Electrical Characteristics for 1.8-V Supply**

$V_+ = 1.65\text{ V to }1.95\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                  | SYMBOL   | TEST CONDITIONS   |                              | T <sub>A</sub> | V <sub>+</sub> | MIN                      | TYP | MAX                      | UNIT |
|--|--|---|------------------------------|----------------|----------------|--------------------------|-----|--------------------------|------|
| Analog Switch                              |  |   |                              |                |                |                          |     |                          |      |
| Analog signal range                        | V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub> |   |                              |                |                | 0                        |     | V <sub>+</sub>           | V    |
| Voltage undershoot                         | V <sub>IKU</sub>                                     | 0 ≥ (I <sub>NC</sub> , I <sub>NO</sub> , or I <sub>COM</sub> ) ≥ − 50 mA                              |                              |                | 1.95 V         |                          |     |                          | V    |
| Peak ON-state resistance                   | r <sub>peak</sub>                                    | 0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>+</sub> ,<br>I <sub>COM</sub> = −4 mA,             | Switch ON,<br>See Figure 13  | 25°C           | 1.65 V         | 13.8                     |     | 60                       | Ω    |
|  |  |   |                              | Full           |                | 120                      |     |                          |      |
| ON-state resistance                        | r <sub>on</sub>                                      | V <sub>NO</sub> or V <sub>NC</sub> = 0,<br>I <sub>COM</sub> = 4 mA                                    | Switch ON,<br>See Figure 13  | 25°C           | 1.65 V         | 5.9                      |     | 15                       | Ω    |
|  |  |   |                              | Full           |                | 15                       |     |                          |      |
|  |  | V <sub>NO</sub> or V <sub>NC</sub> = 1.65 V,<br>I <sub>COM</sub> = −4 mA                              |                              | 25°C           |                | 12.8                     |     | 40                       |      |
|  |  |   |                              | Full           |                | 45                       |     |                          |      |
| ON-state resistance match between channels | Δr <sub>on</sub>                                     | V <sub>NO</sub> or V <sub>NC</sub> = 1.15 V,<br>I <sub>COM</sub> = −4 mA,                             | Switch ON,<br>See Figure 13  | 25°C           | 1.65 V         | 0.1                      |     | 0.5                      | Ω    |
|  |  |   |                              | Full           |                | 0.8                      |     |                          |      |
| ON-state resistance flatness               | r <sub>on(flat)</sub>                                | 0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>+</sub> ,<br>I <sub>COM</sub> = −4 mA,             | Switch ON,<br>See Figure 13  | 25°C           | 1.65 V         | 26.5                     |     | 60                       | Ω    |
|  |  |   |                              | Full           |                | 80                       |     |                          |      |
| NC, NO OFF leakage current                 | I <sub>NC(OFF)</sub> ,<br>I <sub>NO(OFF)</sub>       | V <sub>NC</sub> or V <sub>NO</sub> = 0 to V <sub>+</sub> ,<br>V <sub>COM</sub> = V <sub>+</sub> to 0, | Switch OFF,<br>See Figure 14 | 25°C           | 1.95 V         | 0                        |     | 0.03                     | μA   |
|  |  |   |                              | Full           |                | 0.05                     |     |                          |      |
|  | I <sub>NC(PWROFF)</sub> ,<br>I <sub>NO(PWROFF)</sub> | V <sub>NC</sub> or V <sub>NO</sub> = 0 to 1.95 V,<br>V <sub>COM</sub> = 1.95 V to 0,                  | Switch OFF,<br>See Figure 14 | 25°C           | 0              | 0.15                     |     | 0.05                     |      |
|  |  |   |                              | Full           |                | 0.75                     |     |                          |      |
| COM OFF leakage current                    | I <sub>COM(PWROFF)</sub>                             | V <sub>COM</sub> = 0 to 1.95 V,<br>V <sub>NC</sub> or V <sub>NO</sub> = 1.95 V to 0,                  | Switch ON,<br>See Figure 14  | 25°C           | 0              | 0.2                      |     | 0.5                      | μA   |
|  |  |   |                              | Full           |                | 1                        |     |                          |      |
| NC, NO ON leakage current                  | I <sub>NC(ON)</sub> ,<br>I <sub>NO(ON)</sub>         | V <sub>NC</sub> or V <sub>NO</sub> = 0 to V <sub>+</sub> ,<br>V <sub>COM</sub> = Open,                | Switch ON,<br>See Figure 15  | 25°C           | 1.95 V         | 0.001                    |     | 0.01                     | μA   |
|  |  |   |                              | Full           |                | 0.02                     |     |                          |      |
| COM ON leakage current                     | I <sub>COM(ON)</sub>                                 | V <sub>NC</sub> or V <sub>NO</sub> = Open,<br>V <sub>COM</sub> = 0 to V <sub>+</sub> ,                | Switch ON,<br>See Figure 15  | 25°C           | 1.95 V         | 0.003                    |     | 0.03                     | μA   |
|  |  |   |                              | Full           |                | 0.05                     |     |                          |      |
| Digital Control Input (IN)                 |  |   |                              |                |                |                          |     |                          |      |
| Input logic high                           | V <sub>IH</sub>                                      |   |                              | Full           |                | V <sub>+</sub><br>× 0.75 |     | 5.5                      | V    |
| Input logic low                            | V <sub>IL</sub>                                      |   |                              | Full           |                | 0                        |     | V <sub>+</sub><br>× 0.25 | V    |
| Input leakage current                      | I <sub>IH</sub> , I <sub>IL</sub>                    | V <sub>I</sub> = 5.5 V or 0   |                              | 25°C           | 1.95 V         | 0.005                    |     | 0.01                     | μA   |
|  |  |   |                              | Full           |                | 0.02                     |     |                          |      |

## Electrical Characteristics for 1.8-V Supply (continued)

$V_+ = 1.65 \text{ V to } 1.95 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                        | SYMBOL                           | TEST CONDITIONS  | $T_A$ | $V_+$            | MIN  | TYP            | MAX | UNIT          |
|----------------------------------|----------------------------------|--|-------|------------------|------|----------------|-----|---------------|
| <b>Dynamic</b>                   |                                  |  |       |                  |      |                |     |               |
| Turn-on time                     | $t_{ON}$                         | $V_{COM} = V_+$ or GND,<br>$R_L = 500 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 17                  | 25°C  | 1.8 V            | 9.5  |                | 23  | ns            |
|                                  |                                  |  | Full  | 1.65 V to 1.95 V |      |                | 24  |               |
| Turn-off time                    | $t_{OFF}$                        | $V_{COM} = V_+$ or GND,<br>$R_L = 500 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 17                  | 25°C  | 1.8 V            | 5.9  |                | 10  | ns            |
|                                  |                                  |  | Full  | 1.65 V to 1.95 V |      |                | 12  |               |
| Output voltage during undershoot | $V_{OUTU}$                       | See Figure 18  |       |                  | 2.5  | $V_{OH} - 0.3$ |     | V             |
| Output voltage during overshoot  | $V_{OUTO}$                       | See Figure 18  |       |                  |      | $V_{OL} + 0.3$ | 2   | V             |
| Break-before-make time           | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$ ,<br>$R_L = 50 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>See Figure 19               | 25°C  | 1.8 V            | 0.5  | 18             | 50  | ns            |
|                                  |                                  |  | Full  | 1.65 V to 1.95 V | 0.5  |                | 55  |               |
| Charge injection                 | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,<br>$C_L = 0.1 \text{ nF}$ ,<br>See Figure 23                              | 25°C  | 1.8 V            |      | –5             |     | pC            |
| NC, NO OFF capacitance           | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch OFF,<br>See Figure 16   | 25°C  | 1.8 V            |      | 5.5            |     | pF            |
| NC, NO ON capacitance            | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or GND,<br>Switch ON,<br>See Figure 16  | 25°C  | 1.8 V            |      | 15.5           |     | pF            |
| COM ON capacitance               | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,<br>See Figure 16   | 25°C  | 1.8 V            |      | 15.5           |     | pF            |
| Digital input capacitance        | $C_I$                            | $V_I = V_+$ or GND,<br>See Figure 16   | 25°C  | 1.8 V            |      | 2.5            |     | pF            |
| Bandwidth                        | BW                               | $R_L = 50 \Omega$ ,<br>Switch ON,<br>See Figure 20   | 25°C  | 1.8 V            |      | 369            |     | MHz           |
| OFF isolation                    | $O_{ISO}$                        | $R_L = 50 \Omega$ ,<br>$f = 10 \text{ MHz}$ ,<br>Switch OFF,<br>See Figure 21                                | 25°C  | 1.8 V            |      | –60            |     | dB            |
| Crosstalk                        | $X_{TALK}$                       | $R_L = 50 \Omega$ ,<br>$f = 10 \text{ MHz}$ ,<br>Switch ON,<br>See Figure 22                                 | 25°C  | 1.8 V            |      | –60            |     | dB            |
| Total harmonic distortion        | THD                              | $R_L = 600 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,<br>$f = 20 \text{ Hz to } 20 \text{ kHz}$ ,<br>See Figure 24 | 25°C  | 1.8 V            |      | 0.4            |     | %             |
| <b>Supply</b>                    |                                  |  |       |                  |      |                |     |               |
| Positive supply current          | $I_+$                            | $V_I = V_+$ or GND,<br>Switch ON or OFF  | 25°C  | 1.95 V           | 0.05 | 0.06           |     | $\mu\text{A}$ |
|                                  |                                  |  | Full  |                  |      | 0.3            |     |               |

## TYPICAL PERFORMANCE

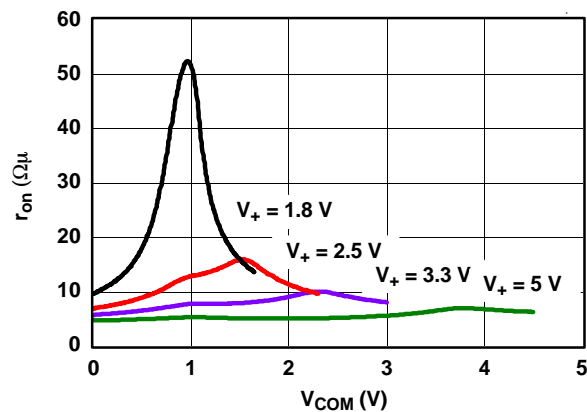


Figure 1.  $r_{on}$  vs  $V_{COM}$

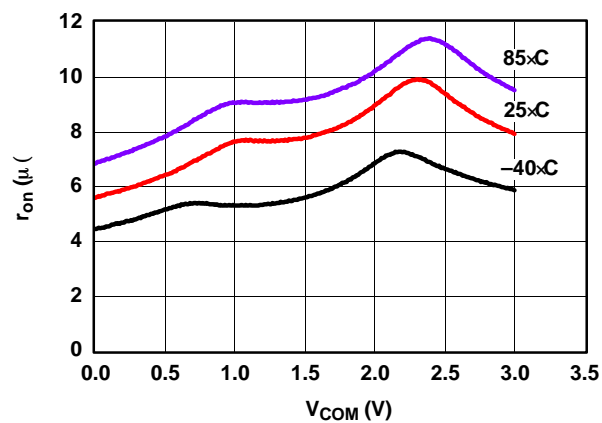


Figure 2.  $r_{on}$  vs  $V_{COM}$  ( $V_+ = 3$  V)

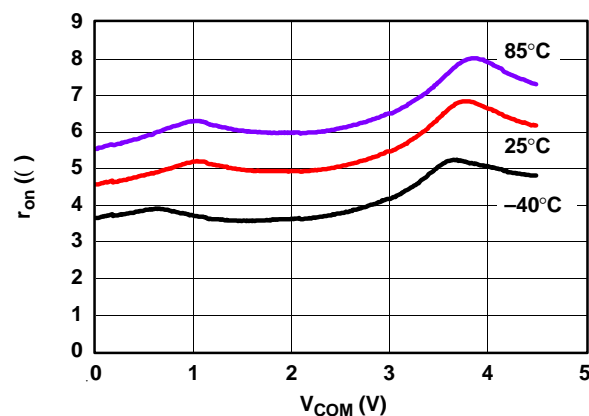


Figure 3.  $r_{on}$  vs  $V_{COM}$  ( $V_+ = 5$  V)

# TYPICAL PERFORMANCE (continued)

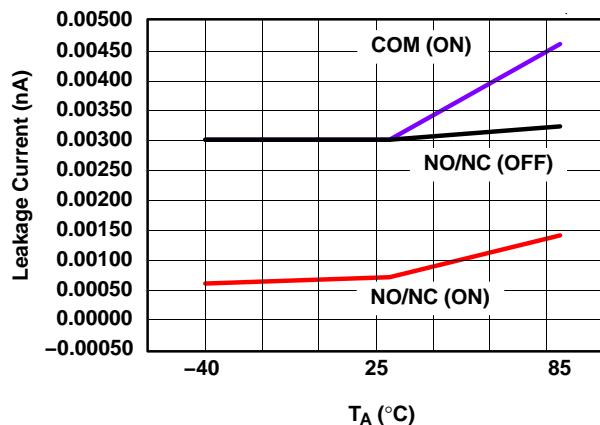


Figure 4. Leakage Current vs Temperature ( $V_+ = 5.5\text{ V}$ )

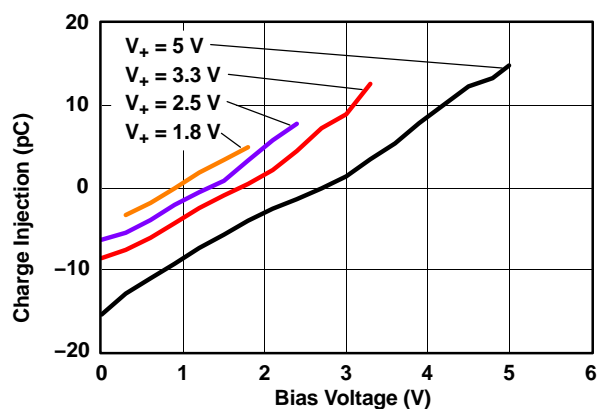


Figure 5. Charge Injection ( $Q_C$ ) vs  $V_{COM}$

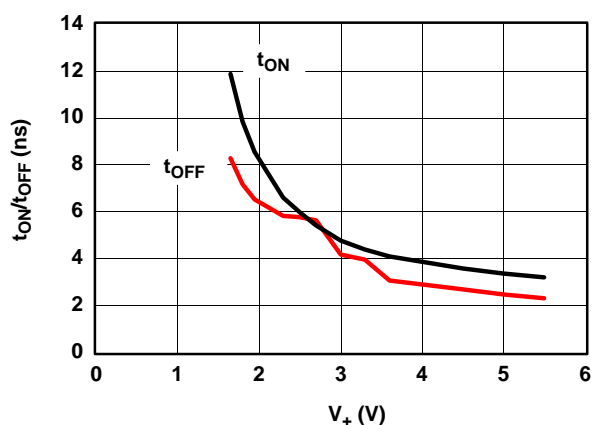


Figure 6.  $t_{ON}$  and  $t_{OFF}$  vs Supply Voltage

### TYPICAL PERFORMANCE (continued)

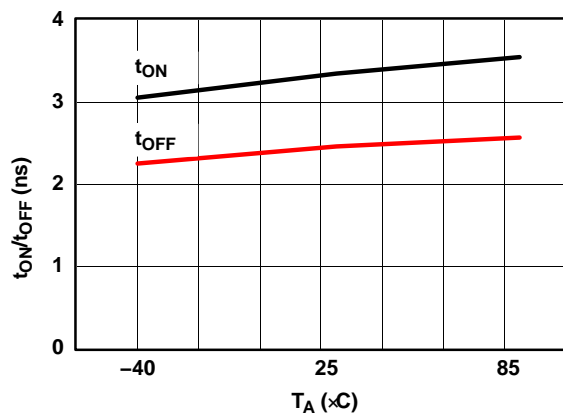


Figure 7.  $t_{ON}$  and  $t_{OFF}$  vs Temperature ( $V_+ = 5$  V)

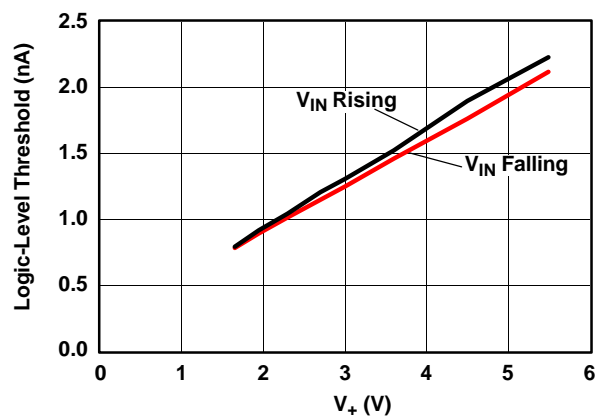


Figure 8. Logic-Level Threshold vs  $V_+$

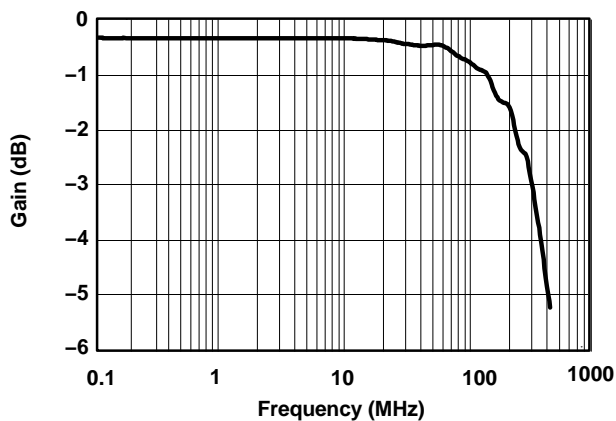


Figure 9. Bandwidth ( $V_+ = 3.3$  V)

TYPICAL PERFORMANCE (continued)

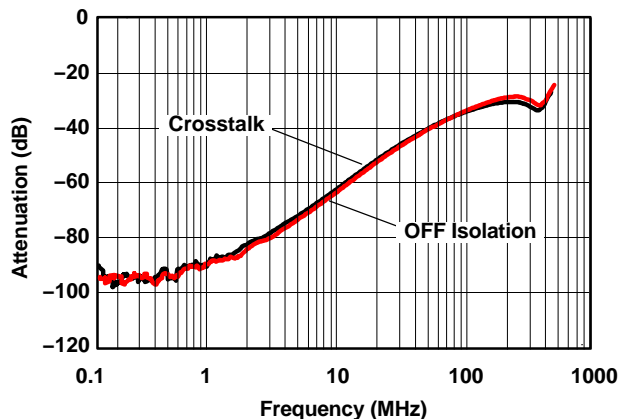


Figure 10. OFF Isolation and Crosstalk ( $V_+ = 3.3$  V)

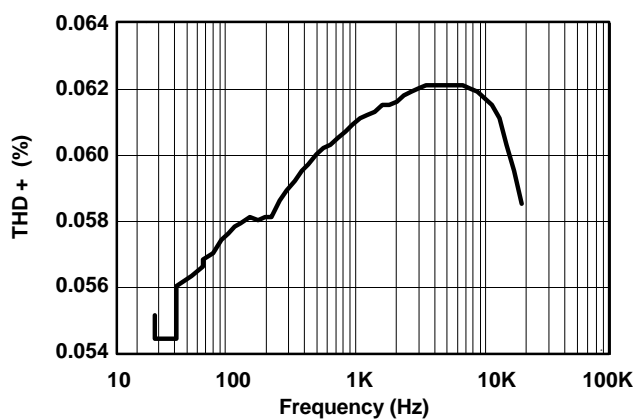


Figure 11. Total Harmonic Distortion (THD) vs Frequency ( $V_+ = 3.3$  V)

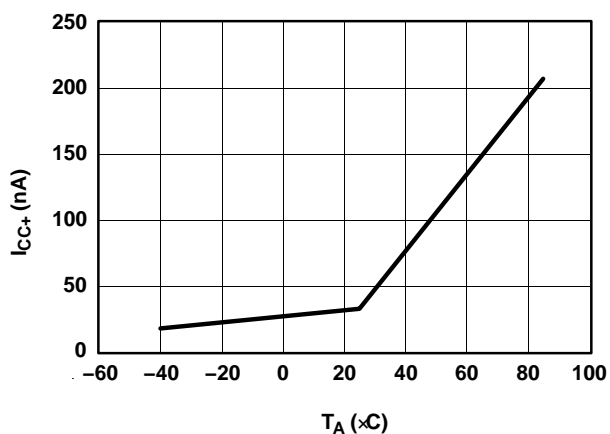


Figure 12. Power-Supply Current vs Temperature ( $V_+ = 5$  V)

**TS5A63157**  
**12- $\Omega$  SPDT ANALOG SWITCH**  
**5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER**

SCDS203–DECEMBER 2005

**PIN DESCRIPTION**

| <b>PIN NO.</b> | <b>NAME</b>    | <b>DESCRIPTION</b>                         |
|----------------|----------------|--|
| 1              | NO             | Normally open                              |
| 2              | GND            | Digital ground                             |
| 3              | NC             | Normally closed                            |
| 4              | COM            | Common                                     |
| 5              | V <sub>+</sub> | Power supply                               |
| 6              | IN             | Digital control to connect COM to NO or NC |



### PARAMETER DESCRIPTION

| SYMBOL            | DESCRIPTION  |
|-------------------|--|
| $V_{COM}$         | Voltage at COM   |
| $V_{NC}$          | Voltage at NC  |
| $V_{NO}$          | Voltage at NO  |
| $r_{on}$          | Resistance between COM and NC or COM and NO ports when the channel is ON   |
| $r_{peak}$        | Peak on-state resistance over a specified voltage range  |
| $\Delta r_{on}$   | Difference of $r_{on}$ between channels in a specific device   |
| $r_{on(flat)}$    | Difference between the maximum and minimum value of $r_{on}$ in a channel over the specified range of conditions   |
| $I_{NC(OFF)}$     | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state   |
| $I_{NC(PWROFF)}$  | Leakage current measured at the NC port during the power-down condition, $V_+ = 0$   |
| $I_{NO(OFF)}$     | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state   |
| $I_{NO(PWROFF)}$  | Leakage current measured at the NO port during the power-down condition, $V_+ = 0$   |
| $I_{NC(ON)}$      | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open  |
| $I_{NO(ON)}$      | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open  |
| $I_{COM(ON)}$     | Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) open   |
| $I_{COM(PWROFF)}$ | Leakage current measured at the COM port during the power-down condition, $V_+ = 0$  |
| $V_{IH}$          | Minimum input voltage for logic high for the control input (IN)  |
| $V_{IL}$          | Maximum input voltage for logic low for the control input (IN)   |
| $V_I$             | Voltage at the control input (IN)  |
| $I_{IH}, I_{IL}$  | Leakage current measured at the control input (IN)   |
| $t_{ON}$          | Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.   |
| $t_{OFF}$         | Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.   |
| $t_{BBM}$         | Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.  |
| $Q_C$             | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$ , $C_L$ is the load capacitance and $\Delta V_{COM}$ is the change in analog output voltage. |
| $C_{NC(OFF)}$     | Capacitance at the NC port when the corresponding channel (NC to COM) is OFF   |
| $C_{NO(OFF)}$     | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF   |
| $C_{NC(ON)}$      | Capacitance at the NC port when the corresponding channel (NC to COM) is ON  |
| $C_{NO(ON)}$      | Capacitance at the NO port when the corresponding channel (NO to COM) is ON  |
| $C_{COM(ON)}$     | Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON  |
| $C_I$             | Capacitance of control input (IN)  |
| $O_{ISO}$         | OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.  |
| $X_{TALK}$        | Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.  |
| BW                | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain.  |
| THD               | Total harmonic distortion is defined as the ratio of the root mean square (RMS) value of the second, third, and higher harmonics to the magnitude of fundamental harmonic.   |
| $I_+$             | Static power-supply current with the control (IN) pin at $V_+$ or GND  |
| $V_{OUTU}$        | Output voltage during an undershoot event. This is measured by turning off a specific channel and applying an undershoot voltage at the input of the switch.   |
| $V_{OUTO}$        | Output voltage during an overshoot event. This is measured by turning off a specific channel and applying an overshoot voltage at the input of the switch.   |

## PARAMETER MEASUREMENT INFORMATION

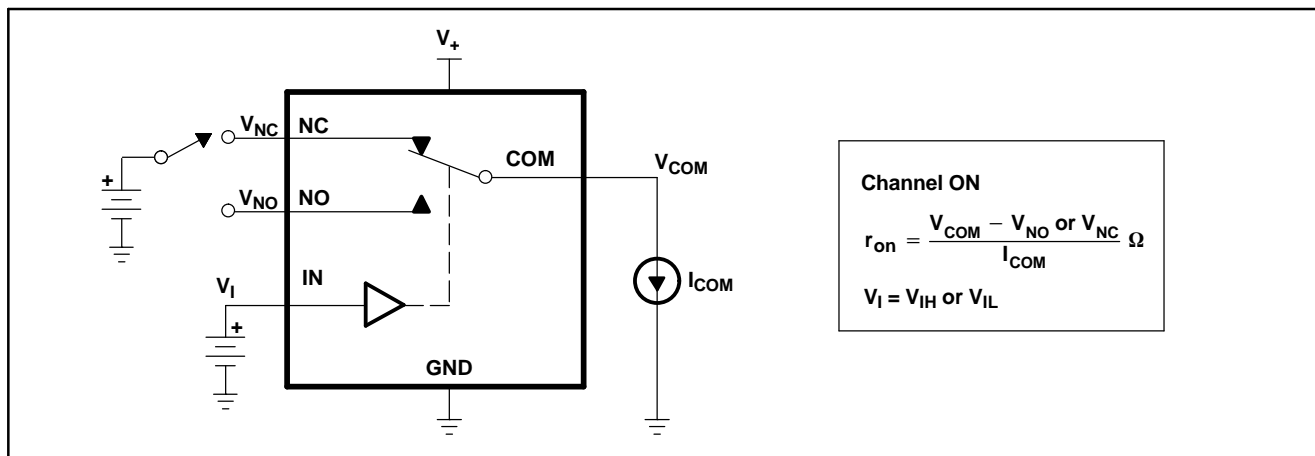


Figure 13. ON-State Resistance ( $r_{on}$ )

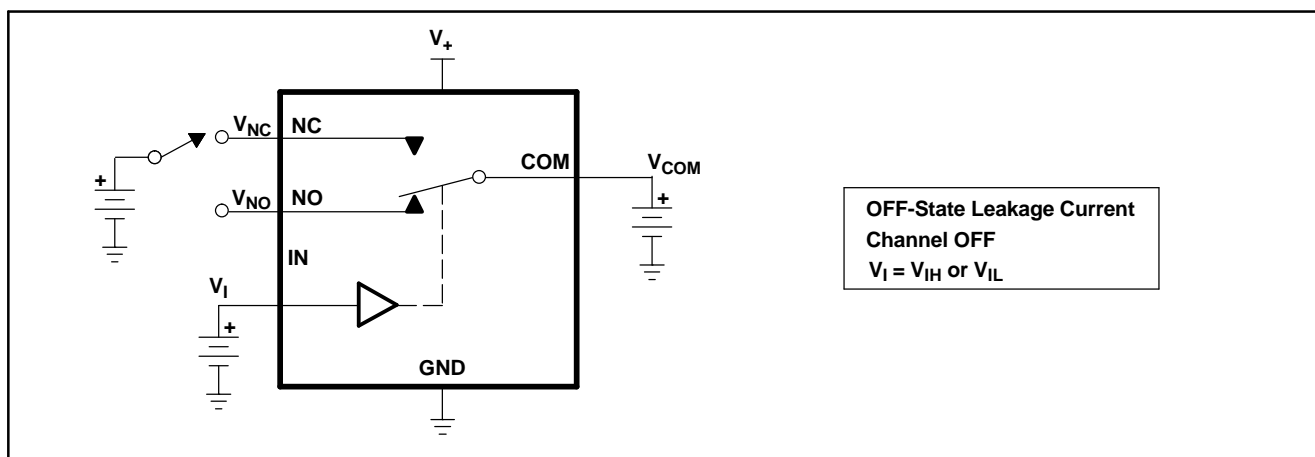


Figure 14. OFF-State Leakage Current  
( $I_{NC(OFF)}$ ,  $I_{NC(PWROFF)}$ ,  $I_{NO(OFF)}$ ,  $I_{NO(PWROFF)}$ ,  $I_{COM(OFF)}$ ,  $I_{COM(PWROFF)}$ )

PARAMETER MEASUREMENT INFORMATION (continued)

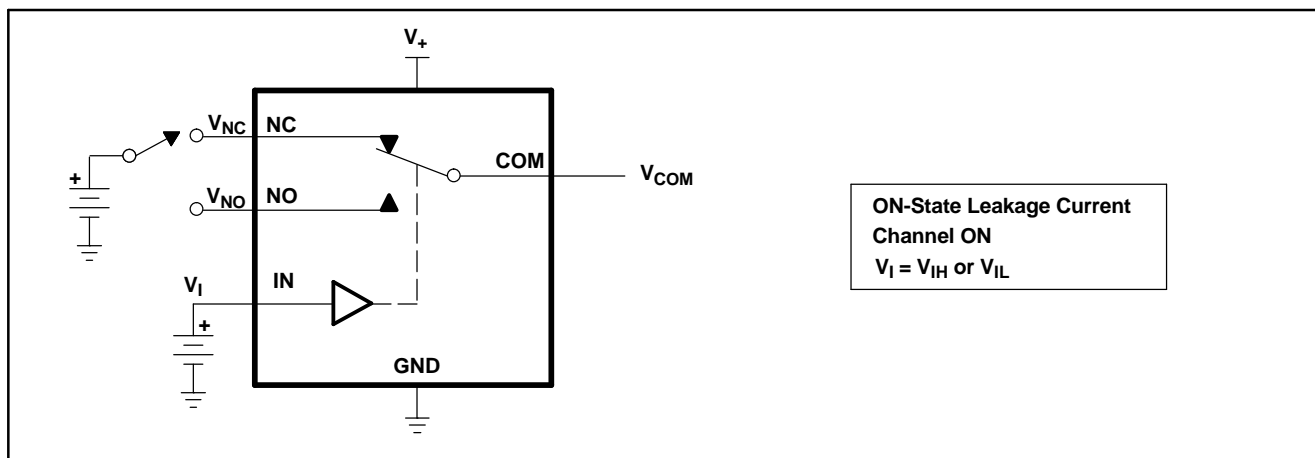


Figure 15. ON-State Leakage Current ( $I_{COM(ON)}$ ,  $I_{NC(ON)}$ ,  $I_{NO(ON)}$ )

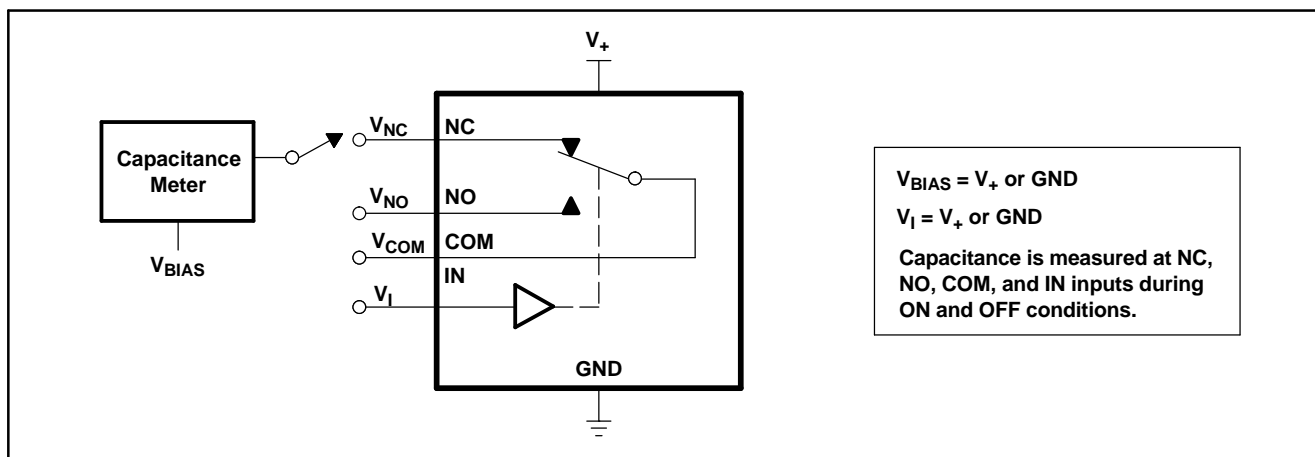
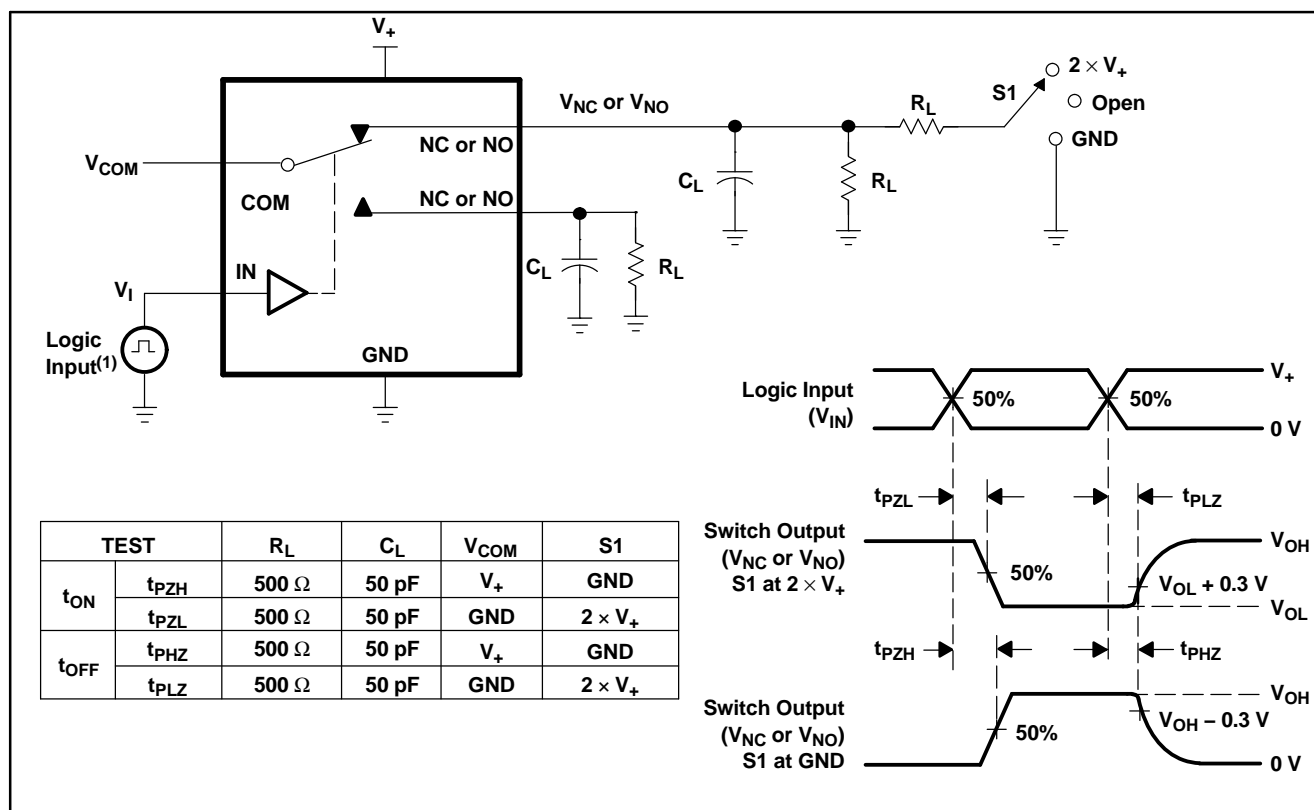


Figure 16. Capacitance ( $C_{IN}$ ,  $C_{COM(ON)}$ ,  $C_{NC(OFF)}$ ,  $C_{NO(OFF)}$ ,  $C_{NC(ON)}$ ,  $C_{NO(ON)}$ )

# PARAMETER MEASUREMENT INFORMATION (continued)



(1) All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10$  MHz,  $Z_O = 50 \Omega$ ,  $t_r < 5$  ns,  $t_f < 5$  ns.

Figure 17. Turn-On ( $t_{ON}$ ) and Turn-Off ( $t_{OFF}$ ) Time

PARAMETER MEASUREMENT INFORMATION (continued)

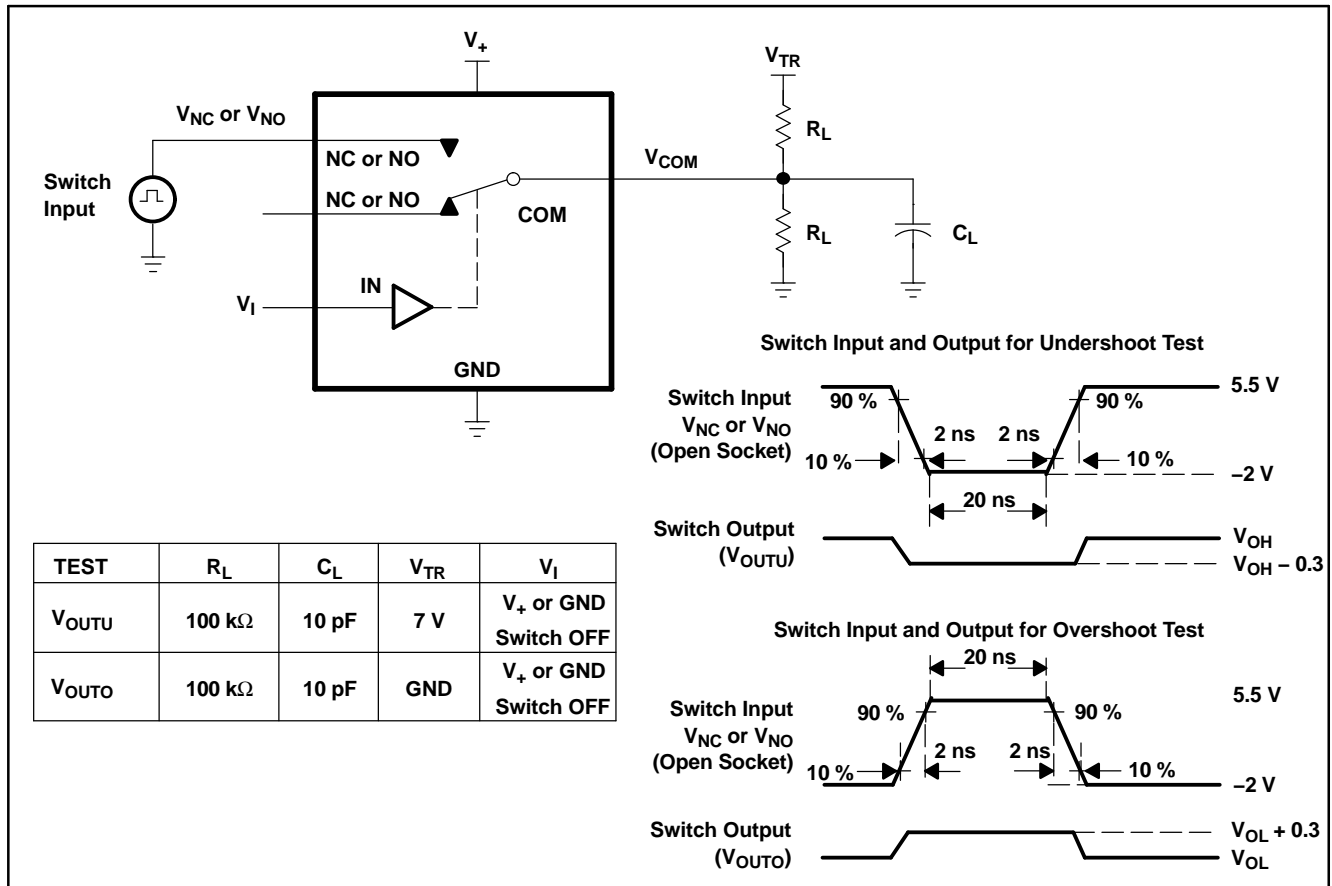
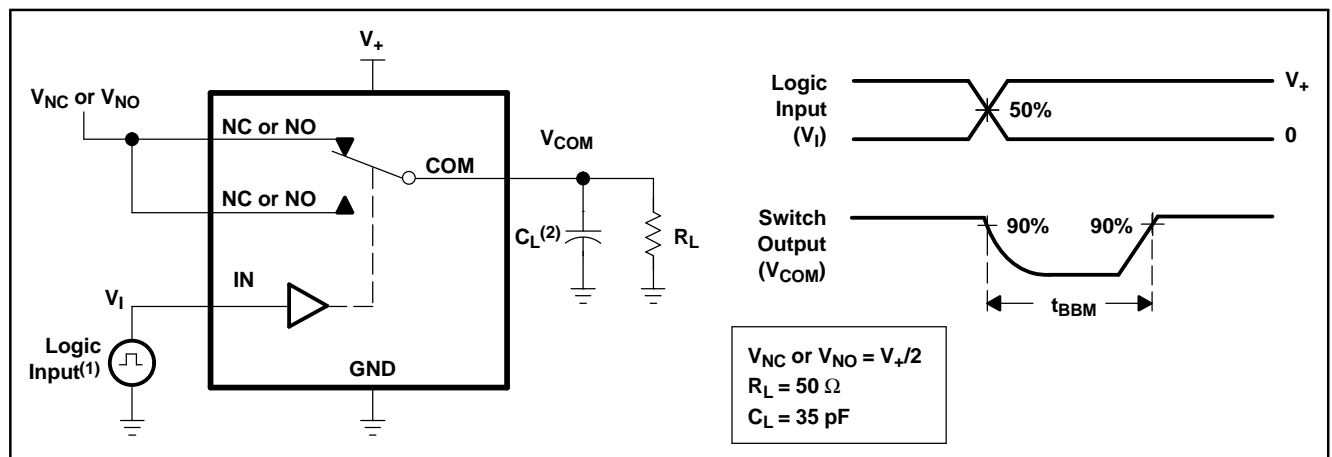


Figure 18. Undershoot and Overshoot Test



- (1) All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r < 5 \text{ ns}$ ,  $t_f < 5 \text{ ns}$ .
- (2)  $C_L$  includes probe and jig capacitance.

Figure 19. Break-Before-Make ( $t_{BBM}$ ) Time

# PARAMETER MEASUREMENT INFORMATION (continued)

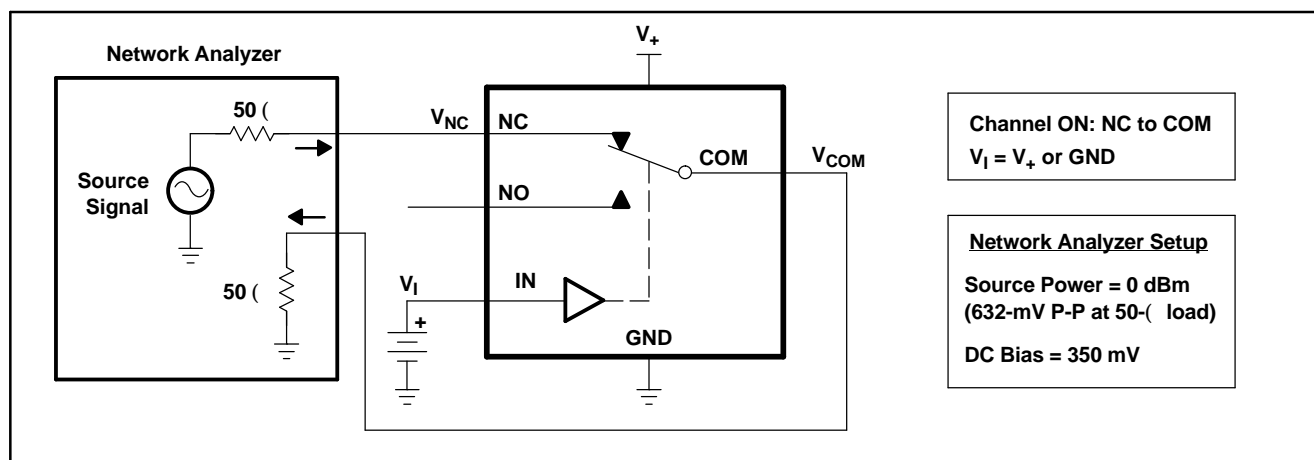


Figure 20. Bandwidth (BW)

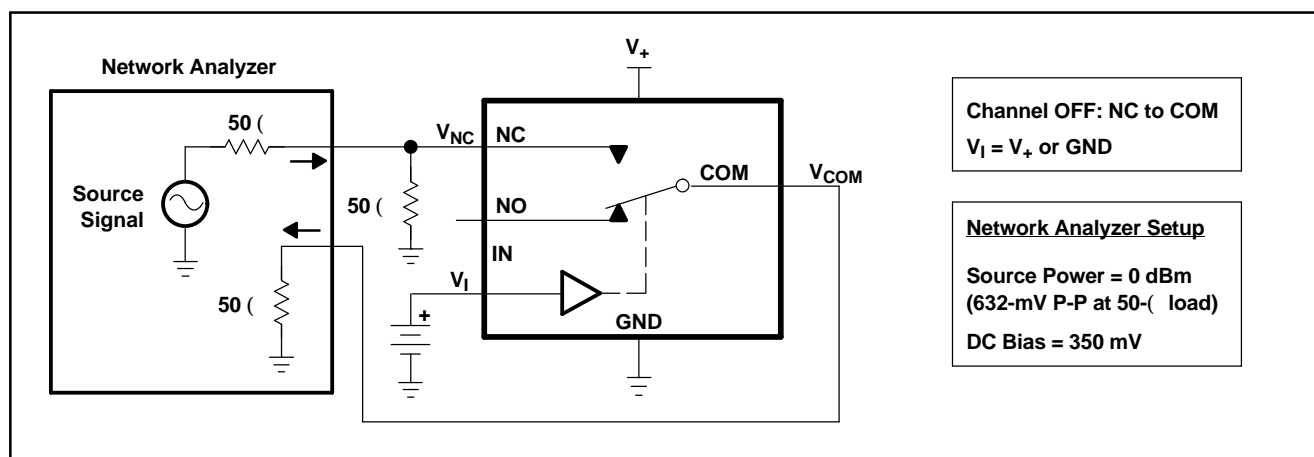


Figure 21. OFF Isolation ( $O_{ISO}$ )

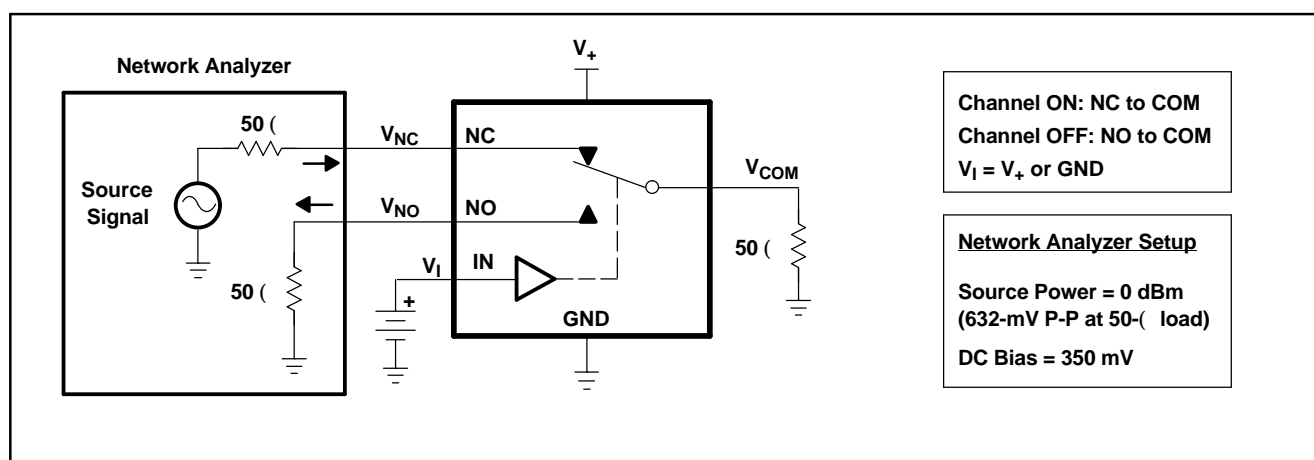
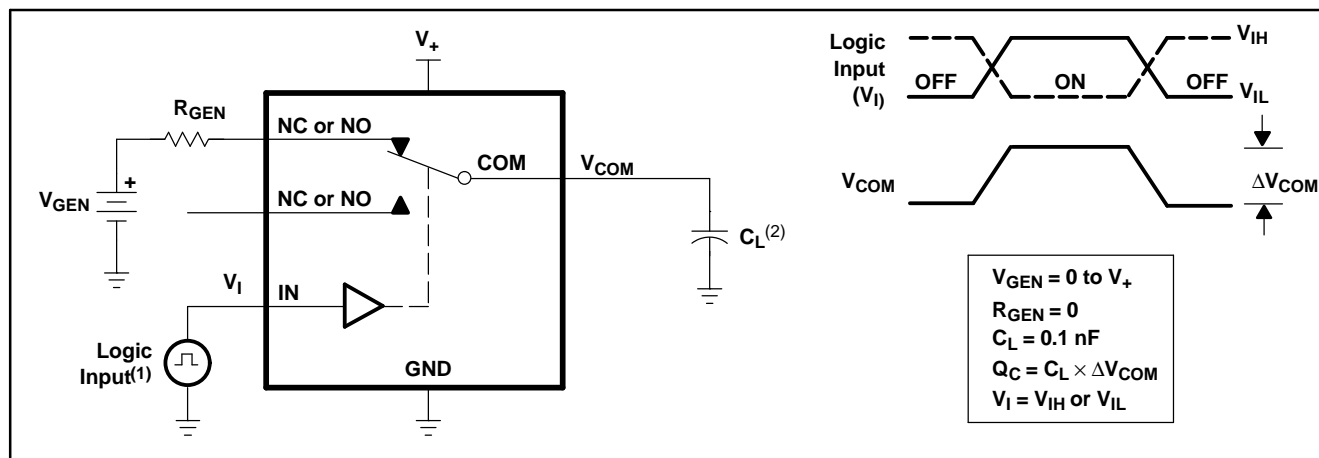


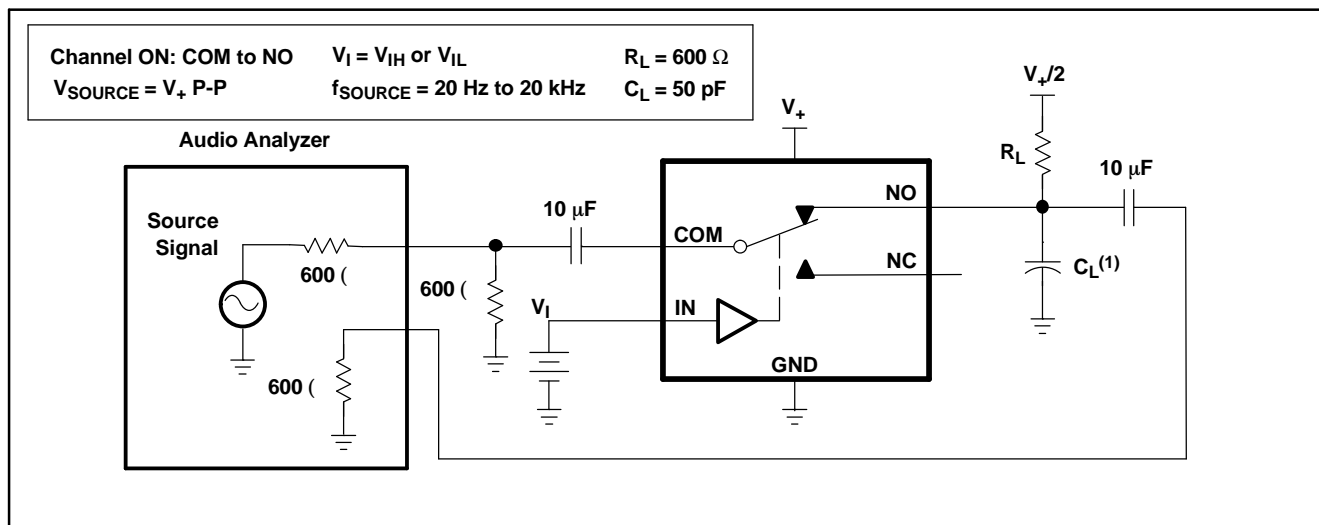
Figure 22. Crosstalk ( $X_{TALK}$ )

PARAMETER MEASUREMENT INFORMATION (continued)



- (1) All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10$  MHz,  $Z_O = 50 \Omega$ ,  $t_r < 5$  ns,  $t_f < 5$  ns.
- (2)  $C_L$  includes probe and jig capacitance.

Figure 23. Charge Injection ( $Q_C$ )



- (1)  $C_L$  includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)

## PACKAGING INFORMATION

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| TS5A63157DBVR    | ACTIVE                | SOT-23       | DBV             | 6    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TS5A63157DBVRE4  | ACTIVE                | SOT-23       | DBV             | 6    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TS5A63157DCKR    | ACTIVE                | SC70         | DCK             | 6    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TS5A63157DCKRE4  | ACTIVE                | SC70         | DCK             | 6    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

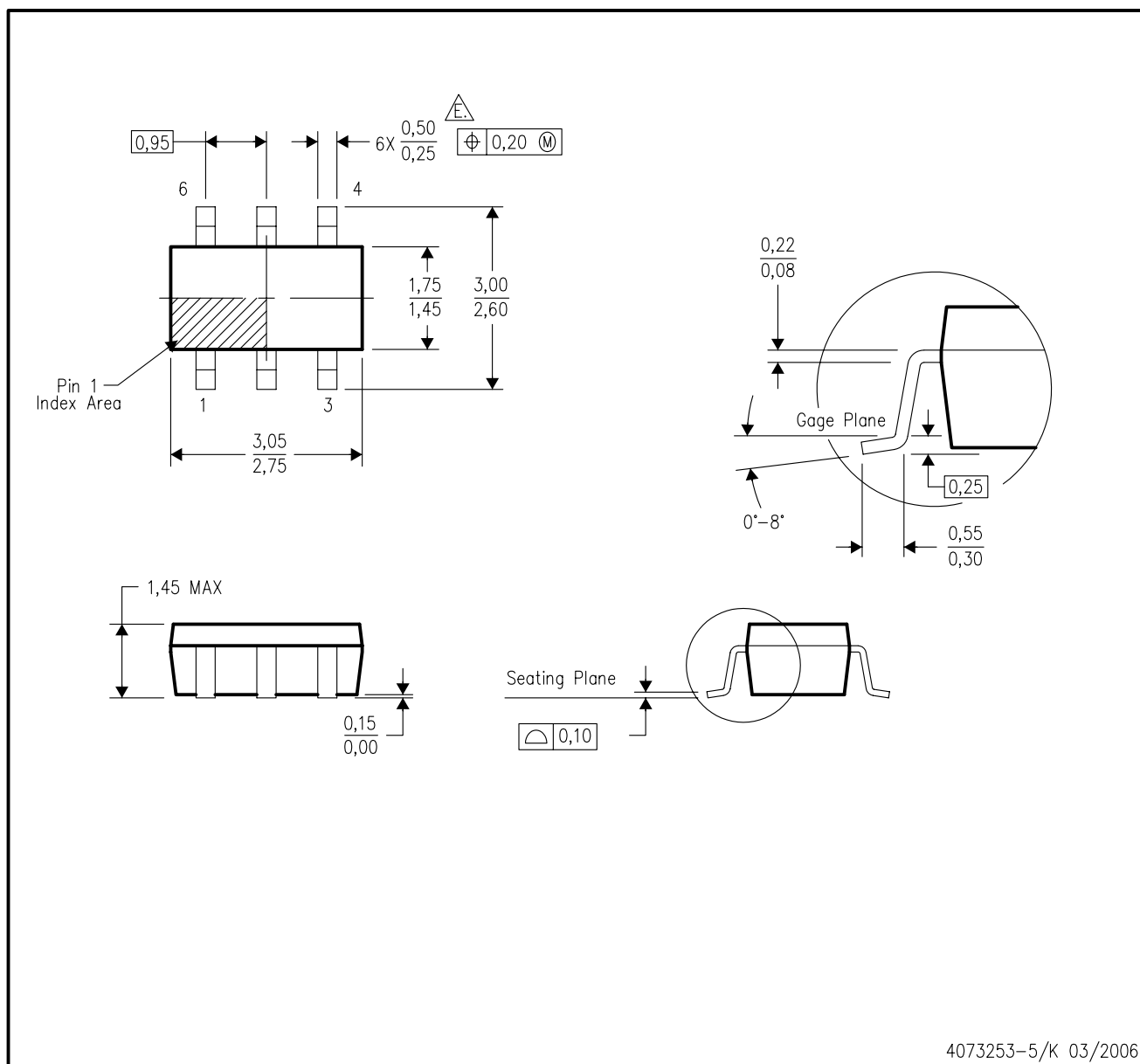
**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



## DBV (R-PDSO-G6)

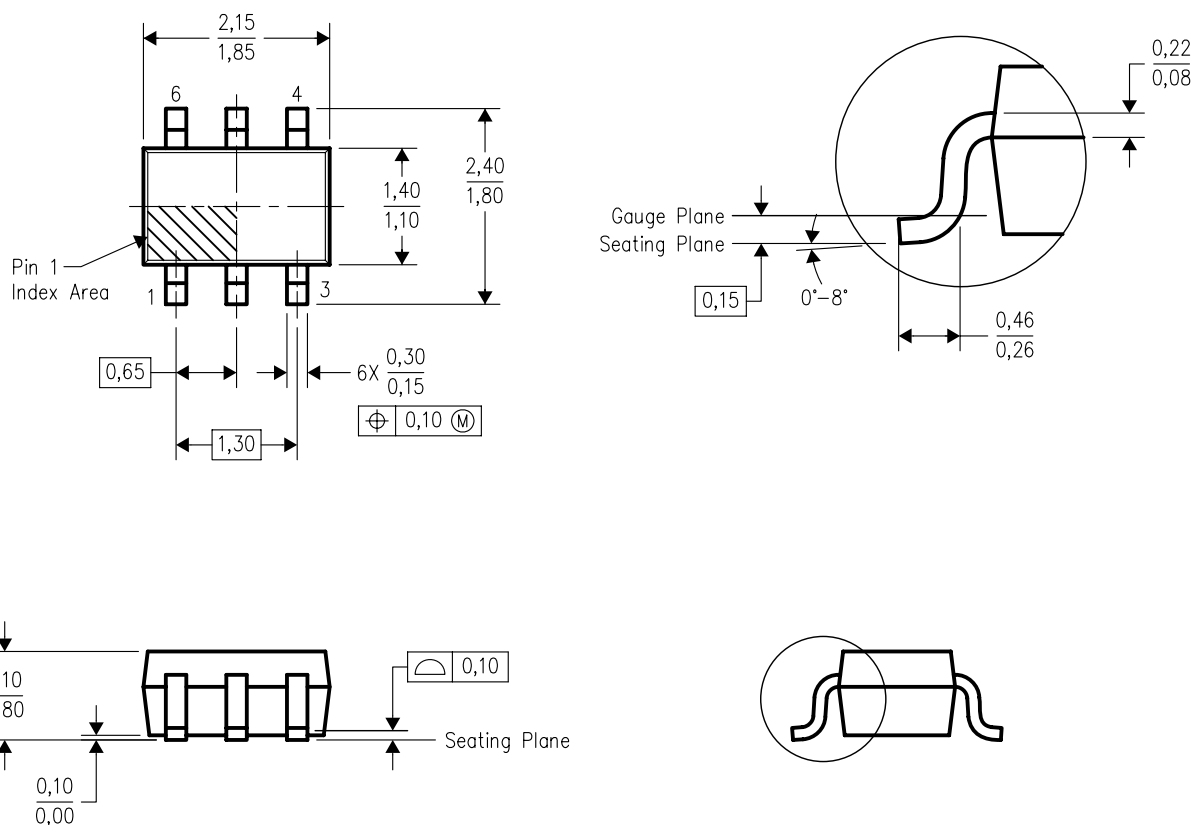
## PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- $\triangle$  Falls within JEDEC MO-178 Variation AB, except minimum lead width.

## DCK (R-PDSO-G6)

## PLASTIC SMALL-OUTLINE PACKAGE



4093553-4/F 07/2006

- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-203 variation AB.

## IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

| <b>Products</b>    |  | <b>Applications</b> |  |
|--------------------|--|---------------------|--|
| Amplifiers         | <a href="http://amplifier.ti.com">amplifier.ti.com</a>             | Audio               | <a href="http://www.ti.com/audio">www.ti.com/audio</a>                   |
| Data Converters    | <a href="http://dataconverter.ti.com">dataconverter.ti.com</a>     | Automotive          | <a href="http://www.ti.com/automotive">www.ti.com/automotive</a>         |
| DSP                | <a href="http://dsp.ti.com">dsp.ti.com</a>                         | Broadband           | <a href="http://www.ti.com/broadband">www.ti.com/broadband</a>           |
| Interface          | <a href="http://interface.ti.com">interface.ti.com</a>             | Digital Control     | <a href="http://www.ti.com/digitalcontrol">www.ti.com/digitalcontrol</a> |
| Logic              | <a href="http://logic.ti.com">logic.ti.com</a>                     | Military            | <a href="http://www.ti.com/military">www.ti.com/military</a>             |
| Power Mgmt         | <a href="http://power.ti.com">power.ti.com</a>                     | Optical Networking  | <a href="http://www.ti.com/opticalnetwork">www.ti.com/opticalnetwork</a> |
| Microcontrollers   | <a href="http://microcontroller.ti.com">microcontroller.ti.com</a> | Security            | <a href="http://www.ti.com/security">www.ti.com/security</a>             |
| Low Power Wireless | <a href="http://www.ti.com/lpw">www.ti.com/lpw</a>                 | Telephony           | <a href="http://www.ti.com/telephony">www.ti.com/telephony</a>           |
|                    |  | Video & Imaging     | <a href="http://www.ti.com/video">www.ti.com/video</a>                   |
|                    |  | Wireless            | <a href="http://www.ti.com/wireless">www.ti.com/wireless</a>             |

Mailing Address: Texas Instruments  
Post Office Box 655303 Dallas, Texas 75265

Copyright © 2006, Texas Instruments Incorporated